# NSN 5961-00-517-7299

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#### Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

#### **Overall Height:**

Between 0.250 inches and 0.450 inches

#### **Overall Width:**

1.050 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

250.0 collector to base voltage, dc and 250.0 collector to emitter saturation voltage and 7.0 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 30.00 amperes source cutoff current

## Power Rating Per Characteristic:

85.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

1 case and 2 pin

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

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